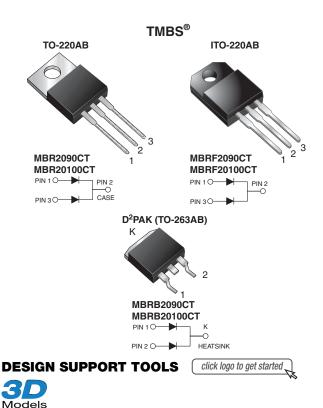
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RoHS

Dual Common-Cathode High Voltage Trench MOS Barrier Schottky Rectifier



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 10 A					
V_{RRM}	90 V to 100 V					
I _{FSM}	150 A					
V_{F}	0.65 V					
T_J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)					
Circuit configuration	Common cathode					

FEATURES

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- · Low forward voltage drop
- High forward surge capability
- · High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER			MBR2090CT	MBR20100CT	UNIT		
Maximum repetitive peak reverse voltage			90	100	V		
Working peak reverse voltage			90	100	V		
Maximum DC blocking voltage		V_{DC}	90	100	V		
Maximum areas forward wealthed assument at T 100 °C	total device	1	20		Α		
Maximum average forward rectified current at $T_C = 133$ °C	per diode	I _{F(AV)}	10				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			150		Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode			130		mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	0.5		Α		
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V _{AC}	1500		V		
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +150		°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	MAX.	UNIT		
Maximum instantaneous forward voltage per diode	I _F = 10 A	T _C = 25 °C		0.80	V		
	I _F = 10 A	T _C = 125 °C	$V_F^{(1)}$	0.65			
	I _F = 20 A	T _C = 125 °C		0.75			
Maximum reverse current per diode at working peak reverse voltage		T _J = 25 °C	I _R ⁽²⁾	100	μΑ		
		T _J = 125 °C		6.0	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT	
Typical thermal resistance per diode	$R_{\theta JA}$	60	-	60	°C/W	
	$R_{ heta JC}$	2.0	3.5	2.0		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20100CT-E3/4W	1.88	4W	50/tube	Tube		
ITO-220AB	MBRF20100CT-E3/4W	1.75	4W	50/tube	Tube		
TO-263AB	MBRB20100CT-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	MBRB20100CT-E3/8W	1.38	8W	800/reel	Tape and reel		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

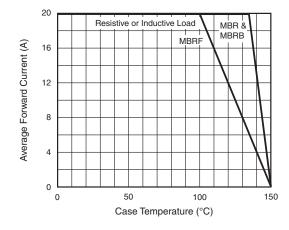


Fig. 1 - Forward Current Derating Curve

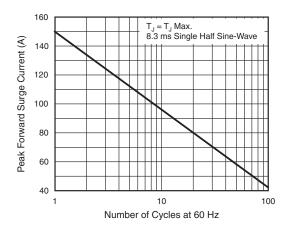


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

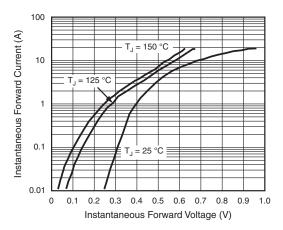


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

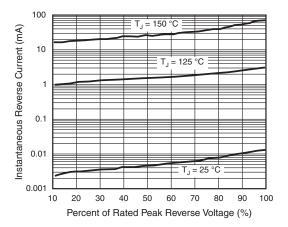


Fig. 4 - Typical Reverse Characteristics Per Diode

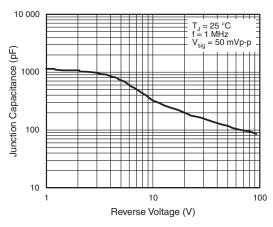


Fig. 5 - Typical Junction Capacitance Per Diode

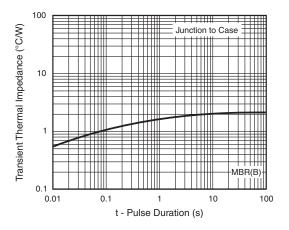


Fig. 6 - Typical Transient Thermal Impedance Per Diode

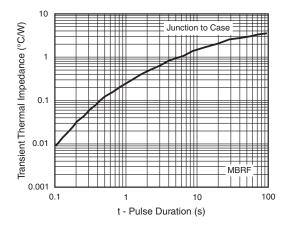


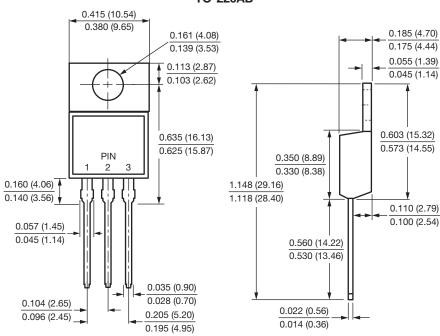
Fig. 7 - Typical Transient Thermal Impedance Per Diode

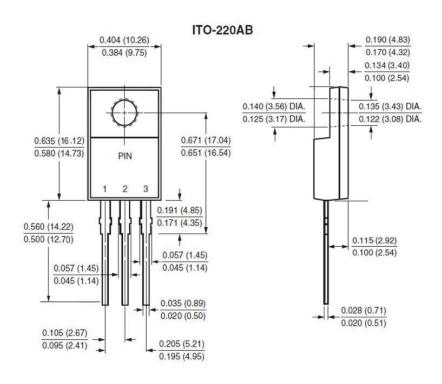
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



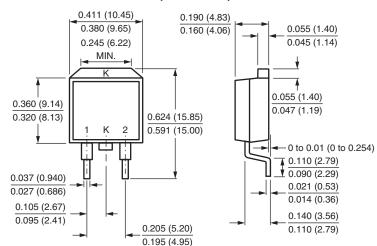




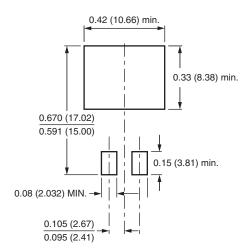
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D²PAK (TO-263AB)



Mounting Pad Layout





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